

Scalable Manufacturing of Multi-Stacked Copper Spiral Inductors Using a Novel Fully Additive Manufacturing Method

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Abstract

This study reports, for the first time, the fully additive fabrication of miniaturized, embedded triple-stacked copper spiral inductors—an unprecedented achievement in multilayer inductor manufacturing. Using our novel Sequential Build-Up–Covalent Bonded Metallization (SBU–CBM) method, we demonstrate an etch-free, room-temperature process capable of producing complex 3D inductor architectures with sub-10 μm features and high vertical integration. Unlike conventional additive, subtractive or hybrid subtractive–additive techniques, the SBU–CBM method enables high-resolution laser-defined patterning, selective electroless copper deposition, and accurate optical alignment—completely eliminating the need for vacuum systems, chemical etching, or thermal sintering. The successful fabrication of three vertically interconnected spiral inductors through 10 μm copper microvias confirms the method’s unmatched capability in fabricating intricate multilayer geometries through a fully additive process. Optical microscopy and X-ray Computed Tomography (XCT) imaging validate the structural integrity, precise interlayer alignment, and continuous electrical connectivity across all layers. Critically, the method achieves uniform miniaturized copper strip widths of 10 μm , underscoring its strength in high-density packaging and next-generation integrated systems. This breakthrough establishes SBU–CBM as a transformative approach for realizing compact, high-performance, and scalable 3D embedded components in future electronic applications.

Key words

Fully additive manufacturing, miniaturized embedded electronic components, multi-stacked spiral inductors.

I. Introduction

The rapid growth of high-performance computing (HPC), fifth-generation (5G) wireless, and miniaturized electronics has intensified the demand for compact, high-Q passive components—particularly embedded inductors. These components are essential for on-chip power management, radio frequency (RF) communication, signal processing, and local energy storage. As integrated circuits (ICs) and system-on-chip (SoC) platforms continue to shrink in lateral dimensions while incorporating increasingly complex functionalities, designers are now targeting inductance densities above ≈ 50 nH/mm² and quality factors (Q) exceeding 30 at 1 GHz—all within footprints of just a few square millimeters. To meet these performance goals, embedded inductors are increasingly implemented in multilayer (multi-stacked) configurations to boost inductance within constrained footprints [1]. However, fabricating such structures poses significant challenges, as inductance is highly dependent on the inductor's geometry and the effective length of the magnetic flux path. Achieving

miniaturization often necessitates multilayer stacking, the use of high-conductivity materials, and precise vertical interconnections—requirements that conventional fabrication methods struggle to fulfill reliably [2].

Each of the conventional approaches—subtractive, additive, and hybrid—faces inherent limitations that constrain their suitability for advanced miniaturized fabrication [3]. Subtractive methods involve complex, multi-step workflows with significant material waste and limited compatibility with flexible or biodegradable substrates. Additive techniques, while more sustainable, often do not provide the resolution and alignment accuracy required for vertical stacking. Hybrid subtractive–additive methods aim to combine the strengths of both approaches, but they often introduce greater process complexity and limited scalability due to extended processing times and alignment challenges [4].

These persistent limitations underscore the urgent need for a new fabrication approach that is fully additive, high-resolution, scalable, and environmentally sustainable. To

address these challenges, our research team at Luleå Technical University (LTU) has developed a novel, fully additive fabrication process called Sequential Build-Up–Covalent Bonded Metallization (SBU–CBM) [5]–[8]. This room-temperature, etch-free method was developed through extensive research in surface chemistry, interface design, and light–matter interactions at the nano/micro scale. It enables precise multilayer stacking and copper microvia formation without vacuum systems, sintering, or harsh chemicals. SBU–CBM supports a wide range of substrates, including flexible polymers, glass interposers, and organic laminates, while achieving strip widths down to $1\ \mu\text{m}$ [7] and via diameters below $10\ \mu\text{m}$ [6]. While the SBU–CBM method can be used to fabricate a wide range of passive electrical components, this study specifically focuses on the fabrication of embedded inductors due to their critical role in advanced electronic systems. In this study, we present—to the best of our knowledge—the first fully additive fabrication of triple-stacked copper spiral inductors using the SBU–CBM method. The results demonstrate reliable multilayer alignment, vertical electrical interconnection, and miniaturized feature formation—making a significant advancement in the additive manufacturing of embedded inductors for next-generation electronic systems.

II. Materials, Equipment, and Methods

A. Materials

The base substrate material (FR-4) was purchased from Digi-Key Electronics Ltd. A UV-curable polyurethane (UV TP-1) and a photosensitive material (HP19) were supplied by Cuptronic (Stockholm, Sweden). Electroless copper deposition solutions (PEC-660 series) obtained from J-KEM International (Stockholm, Sweden). All materials and chemicals were used as received, with no additional purification or pre-treatment.

B. Equipment

A Dymax ECE 5000 flood UV lamp curing system was used to cure the polyurethane. A gallium-nitride (GaN) laser writer machine (LW405B by MICROTECH, Italy) with a wavelength of $375\ \text{nm}$ was used for planar patterning. A diode-pumped picosecond (ps) Nd:YAG laser machine (PL2210 series) was employed for microvia creation. This machine generated $266\ \text{nm}$ laser pulses with a $20\ \text{ps}$ pulse duration at a repetition rate of up to $2\ \text{kHz}$. A Zeiss Axioscope 7 optical microscope was used for surface imaging of the fabricated samples. For three-dimensional structural analysis, the Zeiss Xradia 620 Versa X-ray Computed Tomography (XCT) machine available at Luleå Technical University (LTU) was used.

C. Computer-Aided Design (CAD) for Mask Generation

Spiral-inductor layout was created in CLEWIN 5.0 (WieWeb Software) running on Windows 10. After optimization of line/space dimensions, the designed CAD file in CIF format was uploaded to LW405B laser writer machine. The writer converted the CIF data into raster exposure commands at a base pixel size of $0.6\ \mu\text{m}$, producing the digital mask shown in Fig. 1(b).

The specific CAD design employed in this study to fabricate the triple-stacked inductor is illustrated in Fig. 1(b). During fabrication, manual alignment of fiducial markers was used for successive layers, enabling sub-micrometer layer-to-layer alignment throughout the multilayer build-up sequence.

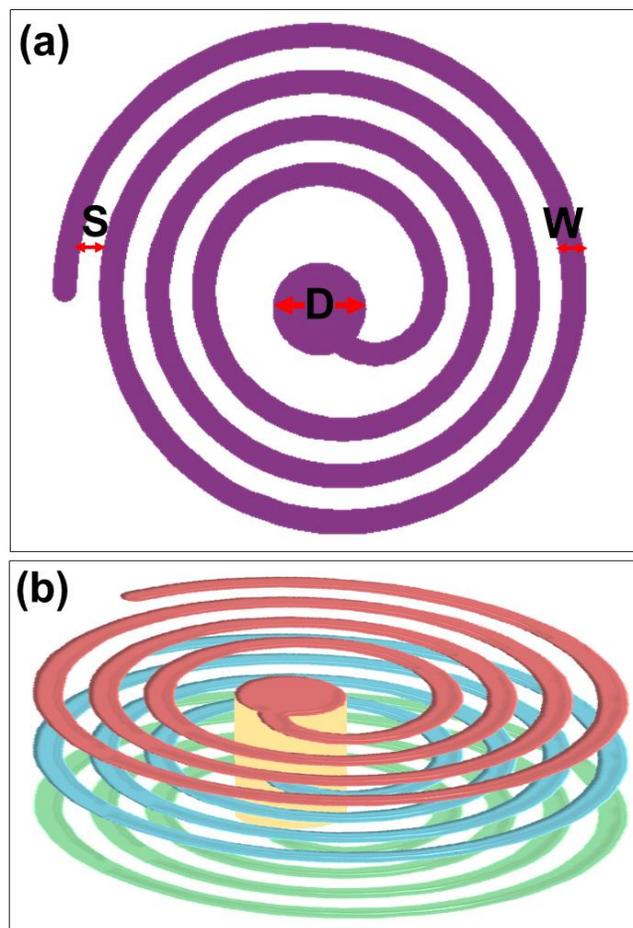


Fig. 1 (a) Computer-aided design (CAD) mask created using CLEWIN software for laser direct writing (LDW) of a planar spiral inductor, with dimensions specified as $D = 50\ \mu\text{m}$, $W = 10\ \mu\text{m}$, and $S = 20\ \mu\text{m}$; (b) Schematic illustration of the conceptual layout for the triple-stacked copper spiral inductor.

D. Fabrication Process

In this research, the process of fabricating embedded triple-stacked copper spiral inductor was carried out through five distinct stages, as follows:

Stage I: Fabricating the First Embedded Copper Spiral Inductor Using the SBU-CBM Method

In this study, FR-4—a widely used printed-circuit-board laminate—was selected as the base substrate. The fabrication process began by cleaning the FR-4 through ultrasonic

cleaning in detergent, acetone, and ethanol, followed by rinsing with deionized (DI) water between each step. Polyurethane (PU) was then spin-coated onto the FR-4 substrate, resulting in the substrate labeled PU1/FR-4. This substrate underwent UV light exposure for three minutes to cure the polyurethane. Following this, a photosensitive material (HP19) was spin-coated onto PU1/FR-4, resulting in the substrate labeled HP19-1/PU1/FR-4. The LW405B machine was then used to pattern the first embedded spiral inductor (SI1) on HP19-1/PU1/FR-4, yielding the substrate

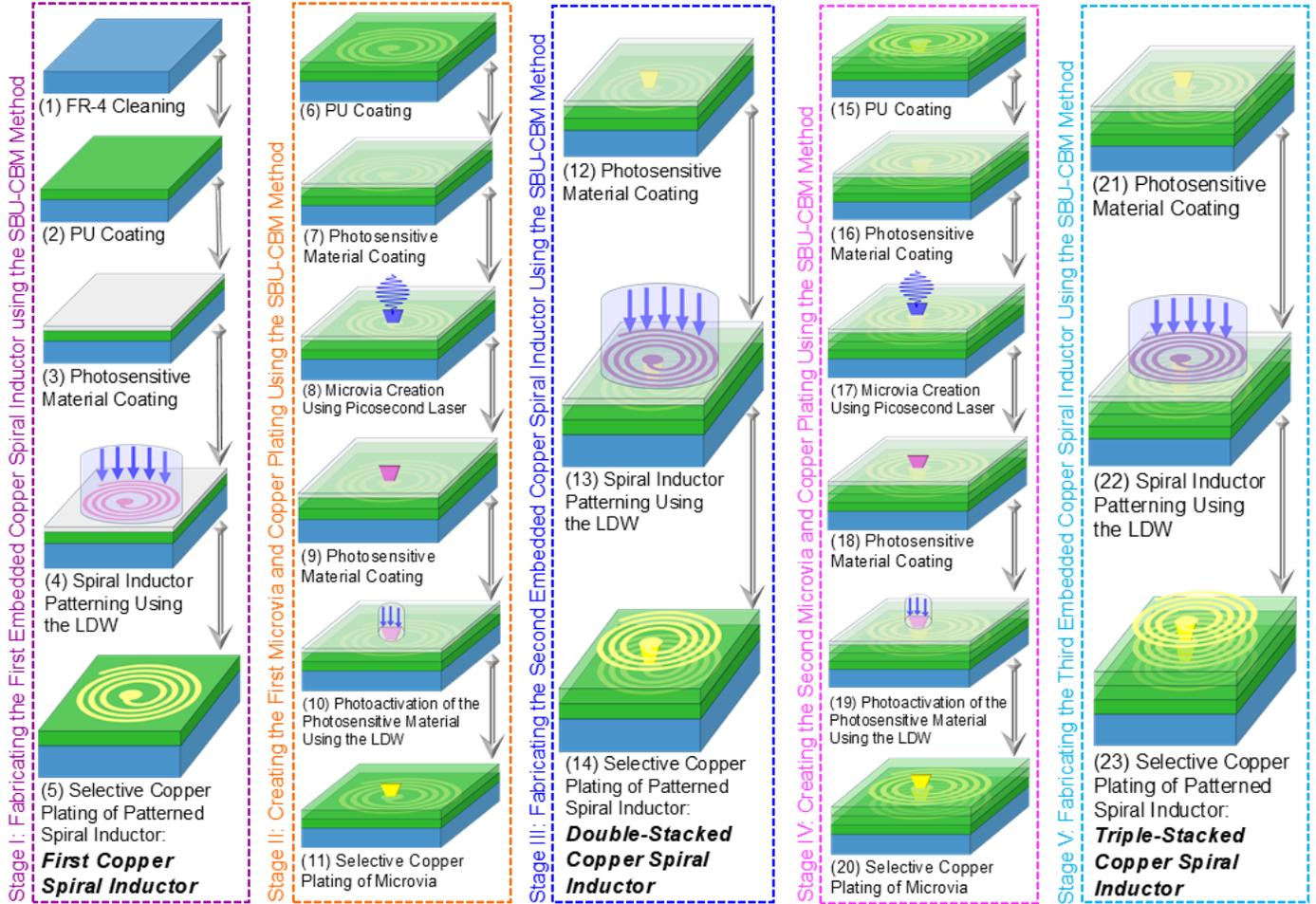


Fig. 2 Schematic diagram illustrating the multi-step process for fabricating embedded triple-stacked copper spiral inductors using the SBU-CBM process. The process involves: Fabricating first embedded copper spiral inductor using the SBU-CBM method (Stage I); Creating the first microvia and copper plating using the SBU-CBM method (Stage II); Fabricating the second embedded copper spiral inductor using the SBU-CBM method (Stage III); Creating the second microvia and copper plating using the SBU-CBM method (Stage IV); Fabricating the third embedded copper spiral inductor using the SBU-CBM method (Stage V).

labeled SI1/HP19-1/PU1/FR-4. After patterning, the substrate was rinsed to remove any unbonded photosensitive material. Electroless copper plating was then carried out as per the supplier's instructions, followed by rinsing with DI water.

Stage II: Creating the First Microvia and Copper Plating Using the SBU-CBM Method

An additional layer of polyurethane was first spin-coated onto the SI1/HP19-1/PU1/FR-4 substrate prepared in Stage I, resulting in the substrate labeled PU2/SI1/HP19-

1/PU1/FR-4. This substrate was then exposed to UV light for three minutes to cure the polyurethane. Next, photosensitive material was spin-coated onto PU2/SI1/HP19-1/PU1/FR-4, producing the substrate labeled HP19-2/PU2/SI1/HP19-1/PU1/FR-4. Immediately following the photosensitive material coating, a microvia was created using PL2210 laser machine, resulting in the substrate labeled Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. To enable selective copper plating of the first microvia, another layer of photosensitive material was spin-coated onto the Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4 substrate. Selective photoactivation was then carried out using the LW405B machine with a CAD mask designed in CLEWIN software. Finally, electroless copper plating solutions were prepared according to the manufacturer's instructions, and the substrate was immersed in the plating baths to selectively deposit copper within the first microvia.

Stage III: Fabricating the Second Embedded Copper Spiral Inductor Using the SBU-CBM Method

The procedures described in Stage I were repeated to build the second embedded copper spiral inductor. First, a new layer of photosensitive material (HP19) was spin-coated onto the Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4 substrate from Stage II, resulting in the substrate labeled HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. The LW405B machine was then used to pattern the second spiral inductor (SI2) on HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4, yielding the substrate labeled SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. After patterning, the substrate was rinsed to remove any unbonded photosensitive material. Electroless copper plating was applied to the substrate, followed by rinsing with DI water.

Stage IV: Creating the Second Microvia and Copper Plating Using the SBU-CBM Method

In Stage IV, the procedures described in Stage II were repeated to form a second microvia that provides vertical connectivity between the second and third spiral inductors. First an additional layer of polyurethane was spin-coated onto the SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4 substrate prepared in Stage III, resulting in the substrate labeled PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. This substrate was then exposed to UV light for three minutes to cure the polyurethane. Next, photosensitive material was spin-coated onto PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4, producing the substrate labeled HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. Immediately following the photosensitive material coating, a microvia was created using PL2210 laser machine, resulting in the substrate labeled Via2/HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-

1/PU1/FR-4. To enable selective copper plating of the second microvia, another layer of photosensitive material was spin-coated onto the Via2/HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4 substrate. Selective photoactivation was then carried out using the LW405B machine with a CAD mask designed in CLEWIN software. Finally, electroless copper plating solutions were prepared according to the manufacturer's instructions, and the substrate was immersed in the plating baths to selectively deposit copper within the second microvia.

Stage V: Fabricating the Third Embedded Copper Spiral Inductor Using the SBU-CBM Method

Finally, the procedures outlined in Stages I and III were repeated to create the third copper spiral inductor, thereby completing the triple-stacked structure. First, a new layer of photosensitive material (HP19) was spin-coated onto the Via2/HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4 substrate from Stage IV, resulting in the substrate labeled HP19-5/Via2/HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. The LW405B machine was then used to pattern the third spiral inductor (SI2) on HP19-5/Via2/HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4, yielding the substrate labeled SI3/HP19-5/Via2/HP19-4/PU3/SI2/HP19-3/Via1/HP19-2/PU2/SI1/HP19-1/PU1/FR-4. After patterning, the substrate was rinsed to remove any unbonded photosensitive material. Electroless copper plating was applied to the substrate, followed by rinsing with DI water.

III. Results and Discussion

To verify that each fabrication step was precisely carried out, microscopy imaging was performed following key stages of the process. The results are presented in Fig. 3. Specifically, Fig. 3(a) shows an optical microscope image taken during Stage I, immediately after patterning using LDW and prior to metallization. This image presents the first embedded spiral inductor patterned using the LDW technique. It highlights the capability of LDW to directly define high-resolution micro-inductors within a polymeric substrate without requiring etching or masks. Fig. 3(b) displays the optical microscope image obtained at the end of Stage I, following metallization. The copper spiral inductor marked with '1' in the image confirms the successful formation of the first embedded copper spiral inductor (SI1). The copper was selectively deposited along the patterned area, demonstrating precise alignment with the LDW-defined structure. Fig. 3(c) presents the top-view optical microscope image captured after Stage III, illustrating the second embedded copper spiral inductor. In this image, label "1" marks the first

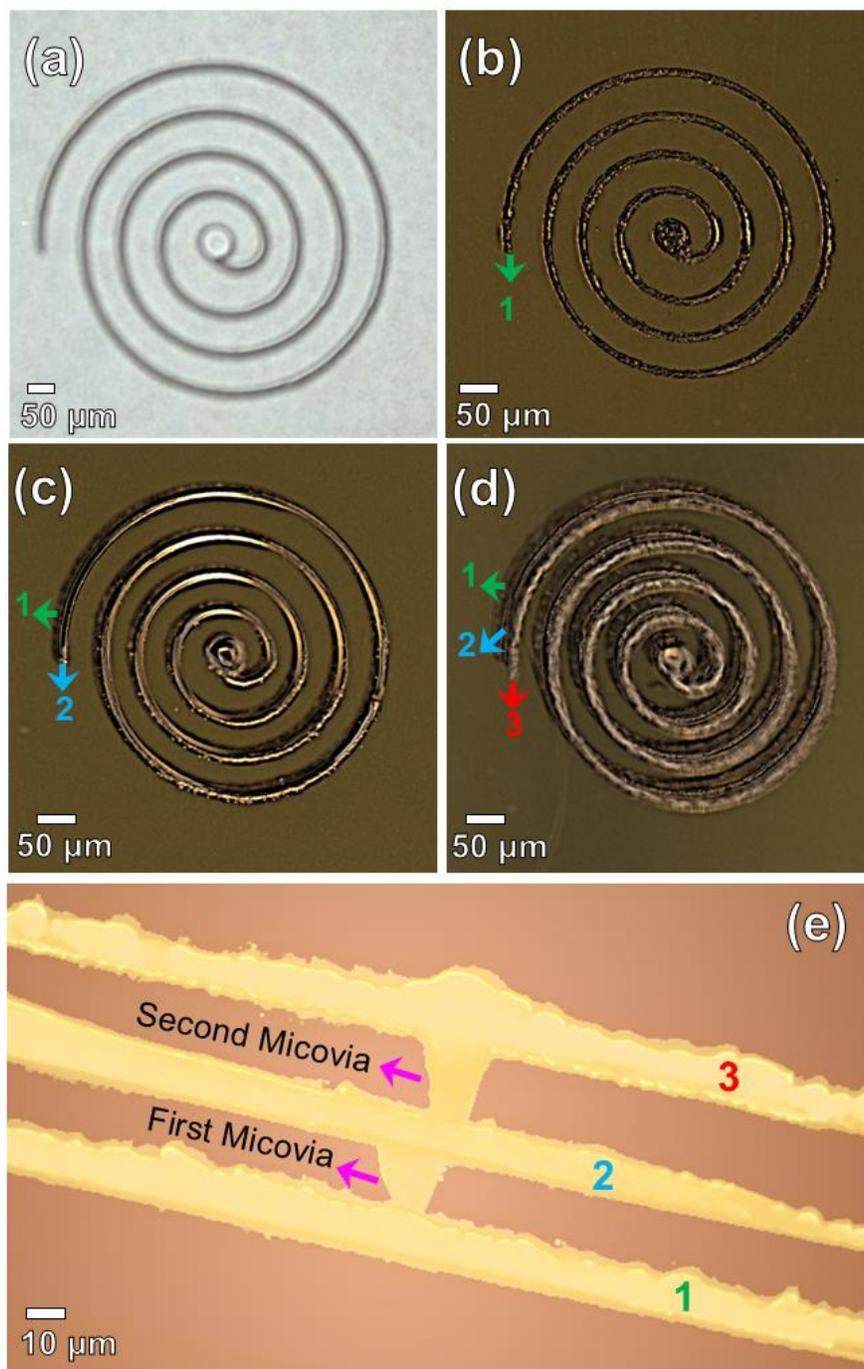


Fig. 3 Optical microscope and XCT images at key fabrication stages: (a) Optical microscope image of the first embedded spiral inductor patterned using LDW prior to metallization; (b) Optical microscope image of the first embedded copper spiral inductor after metallization at the end of Stage I; (c) Top-view optical microscope image of the second copper spiral inductor obtained at the end of Stage III, showing two aligned embedded copper spiral inductors; (d) Optical microscope image of the third copper spiral inductor at the end of Stage V, illustrating the precise alignment of the triple-stacked copper spiral inductors; (e) Cross-sectional XCT image of the embedded triple-stacked copper spiral inductors in a 3D perspective. Label “1” in Fig. 3b–d marks the first (bottom-layer) copper spiral inductor; label “2” in Fig. 3c–d denotes the second (middle-layer) copper spiral inductor; and label “3” in Fig. 3d identifies the third (top-layer) copper spiral inductor.

(bottom-layer) copper spiral inductor, while label “2” identifies the second (top-layer) copper spiral inductor. The clear distinction and alignment between the layers affirm the successful layer-by-layer build-up of the structure. Fig. 3(d) shows the optical microscope image acquired after Stage V, revealing the completed triple-stacked copper spiral inductor. Here, label “1” corresponds to the first copper spiral inductor (bottom-layer), “2” to the second copper spiral inductor (middle-layer), and “3” to the third copper spiral inductor (top-layer). The precise alignment of each copper spiral inductor indicates the robustness of the developed fabrication sequence and alignment accuracy across multiple layers. Across all stages (Fig. 3a–d), the fabricated copper strips exhibit a uniform width of approximately 10 μm , which is consistent with the CAD design specifications. One of the major challenges in additive manufacturing of embedded structures is achieving high selectivity during copper deposition to avoid unwanted bridging or leakage between conductive lines. The presented images clearly demonstrate that copper was deposited only in the intended spiral regions without any visible leakage or spreading between strip lines. This level of precision is a key advantage of the SBU-CBM method over conventional additive approaches. To further verify the integrity and connectivity of the multilayer structure, XCT was performed using the Zeiss Xradia 620 Versa system at Luleå University of Technology. As shown in Fig. 3(e), the XCT image confirms the vertical stacking and interconnection of all three copper spiral inductors. The internal copper microvia that connects the layers is clearly visible, demonstrating the successful formation of a continuous electrical pathway through the multilayer structure. This non-destructive imaging technique not only validates the fabrication accuracy and structural integrity of the final inductor assembly but also provides critical insights into the spatial arrangement and encapsulation of the internal features. The successful combination of LDW patterning, selective metallization, and precise vertical interconnection underscores the effectiveness and scalability of the SBU-CBM process for fabricating high-density, multilayer embedded electronic components.

III. Conclusion

In summary, this work presents, for the first time, the fully additive fabrication of miniaturized, embedded triple-stacked copper spiral inductors using our novel Sequential Build-Up–Covalent Bonded Metallization (SBU–CBM) method. The demonstrated approach eliminates the need for vacuum systems, chemical etching, or thermal sintering while maintaining high resolution and precise vertical interconnectivity. The successful realization of three

interconnected spiral inductors demonstrates the robustness and accuracy of the developed fabrication process. These structures, which feature 10 μm copper microvias and 10 μm -wide spiral strip lines, also confirm its scalability for high-density embedded components. Beyond proving manufacturing feasibility, this work highlights the critical importance of precise microvia alignment and selective metallization for achieving low-loss vertical connections and structural integrity across multiple layers. The room-temperature additive processing enabled by the SBU–CBM method provides compatibility with temperature-sensitive substrates and facilitates integration with flexible and heterogeneous electronics, while selective electroless copper plating offers a clean and mask-free approach for high-density electrical packaging. These findings position the SBU–CBM method as an enabling technology for next-generation miniaturized and embedded passive components. Such components are essential in modern electronics where compact, high-performance, and energy-efficient electronic components are required. They are particularly critical for systems supporting advanced computing hardware, AI processors, and quantum devices. Future research will focus on comprehensive electrical characterization of the fabricated inductors, integration with other passive and active components, scaling the method to larger and more complex system-in-package platforms, and exploring new substrate materials for extreme environments. The research results presented in this study set a new benchmark in embedded inductor fabrication. They open a promising pathway for the broader adoption of additive manufacturing in advanced system-in-package and integrated circuit platforms, reinforcing its potential as a key enabler of future.

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Note: References 5–8 are our previous works and have been reused where relevant.